# NSN 5962-01-247-3409

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

0.760 inches

#### **Body Width:**

0.270 inches

## **Body Height:**

0.155 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and programmable and bipolar and 3-state output

## Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

10 input

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## Time Rating Per Chacteristic:

85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

## Memory Capacity:

Unknown

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

16 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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